

# N-Channel Reduced Q<sub>g</sub>, Fast Switching MOSFET

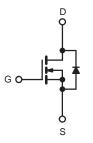
PRODUCT SUMMARY			
V <sub>DS</sub> (V)	$R_{DS(on)}\left(\Omega\right)$	I <sub>D</sub> (A)	
60	0.028 at V <sub>GS</sub> = 10 V	7	
	0.04 at V <sub>GS</sub> = 4.5 V	5.5	

#### **FEATURES**

- DT-Trench Power MOSFET
- 175 °C Maximum Junction Temperature
- Compliant to RoHS Directive 2002/95/EC







N-Channel MOSFET

<b>ABSOLUTE MAXIMUM RATINGS</b> T <sub>A</sub> = 25 °C, unless otherwise noted						
Parameter		Symbol	10 s	Steady State	Unit	
Drain-Source Voltage		$V_{DS}$	60		V	
Gate-Source Voltage		$V_{GS}$	± 20			
Continuous Drain Current (T <sub>.I</sub> = 175 °C) <sup>a</sup>	T <sub>A</sub> = 25 °C	I <sub>D</sub>	7	6.0		
Continuous Diain Current (1) = 173 C)	T <sub>A</sub> = 70 °C		6.1	5.0	Α	
Pulsed Drain Current		I <sub>DM</sub>	40		^	
Avalanche Current		I <sub>AS</sub>	15			
Single Pulse Avalanche Energy		E <sub>AS</sub>	11		mJ	
Maximum Dawar Dissipation	T <sub>A</sub> = 25 °C	- P <sub>D</sub>	3.3	1.7	W	
Maximum Power Dissipation <sup>a</sup>	T <sub>A</sub> = 70 °C		2.3	1.2		
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	- 55 to 175		°C	

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Mariana la Ambiant	t ≤ 10 s	R <sub>thJA</sub>	36	45	°C/W
Maximum Junction-to-Ambient <sup>a</sup>	Steady State		75	90	
Maximum Junction-to-Foot (Drain)	Steady State	R <sub>thJF</sub>	17	20	

a. Surface Mounted on 1" x 1" FR4 board.



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Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static							
Drain-Source Breakdown Voltage	$V_{DS}$	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$	60			V	
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	1		3	V	
Gate-Body Leakage	$I_{GSS}$	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			± 100	nA	
Zana Cata Valtana Duais Course	I <sub>DSS</sub>	$V_{DS} = 60 \text{ V}, V_{GS} = 0 \text{ V}$			1	μА	
Zero Gate Voltage Drain Current		V <sub>DS</sub> = 48 V, V <sub>GS</sub> = 0 V, T <sub>J</sub> = 55 °C			20		
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{DS} \ge 5 \text{ V}, V_{GS} = 10 \text{ V}$	40			Α	
		$V_{GS} = 10 \text{ V}, I_D = 6.0 \text{ A}$		0.02	0.028		
	R <sub>DS(on)</sub>	$V_{GS} = 10 \text{ V}, I_D = 5 \text{ A}, T_J = 125 ^{\circ}\text{C}$		0.031	0.037	Ω	
Drain-Source On-State Resistance <sup>a</sup>		$V_{GS} = 10 \text{ V}, I_D = 5 \text{ A}, T_J = 175 \text{ °C}$		0.039	0.047		
		$V_{GS} = 4.5 \text{ V}, I_D = 3 \text{ A}$		0.035	0.04		
Forward Transconductance <sup>a</sup>	9 <sub>fs</sub>	$V_{DS} = 15 \text{ V}, I_{D} = 5 \text{ A}$		25		S	
Diode Forward Voltage <sup>a</sup>	$V_{SD}$	I <sub>S</sub> = 5 A, V <sub>GS</sub> = 0 V		0.8	1.2	V	
Dynamic <sup>b</sup>							
Total Gate Charge	$Q_g$			18	27		
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS} = 30 \text{ V}, V_{GS} = 10 \text{ V}, I_{D} = 5.0 \text{ A}$		3.4		nC	
Gate-Drain Charge	$Q_{gd}$			5.3			
Gate Resistance	$R_g$	$V_{GS} = 0.1 \text{ V, f} = 5 \text{ MHz}$	0.5	1.4	2.4	Ω	
Turn-On Delay Time	t <sub>d(on)</sub>			10	20		
Rise Time	t <sub>r</sub>	$V_{DD}$ = 30 V, $R_L$ = 30 $\Omega$		10	20		
Turn-Off Delay Time	t <sub>d(off)</sub>	$I_D \cong 5 A$ , $V_{GEN} = 10 V$ , $R_g = 6 \Omega$		25	50	ns	
Fall Time	t <sub>f</sub>			12	24		
Source-Drain Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> = 5 A, dI/dt = 100 A/μs		50	80		

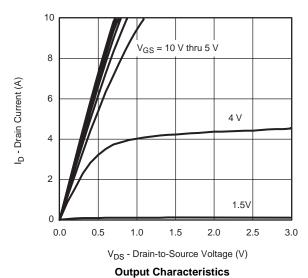
#### Notes:

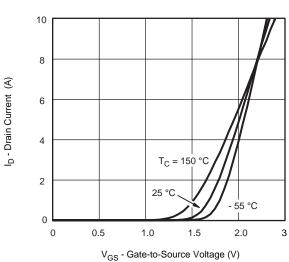
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- a. Pulse test; pulse width  $\leq$  300 µs, duty cycle  $\leq$  2 %.
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

## TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted





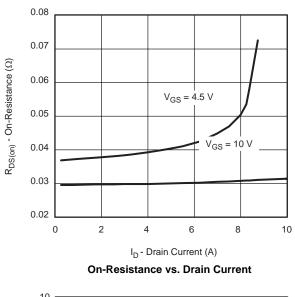
**Transfer Characteristics** 

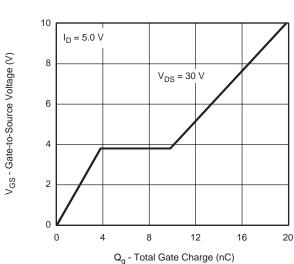


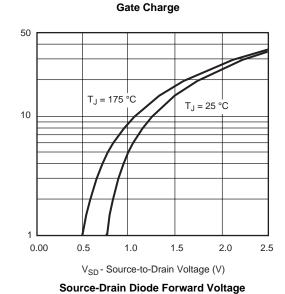
I<sub>S</sub> - Source Current (A)

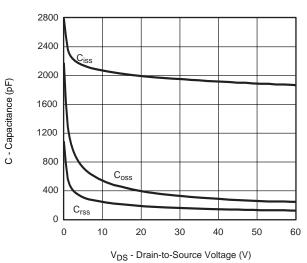
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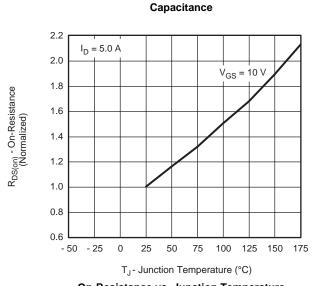
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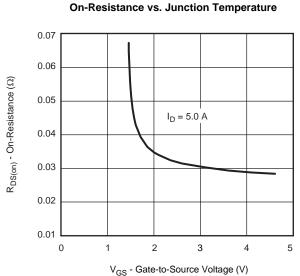








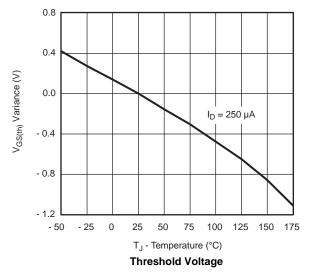


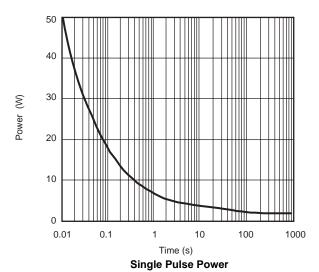


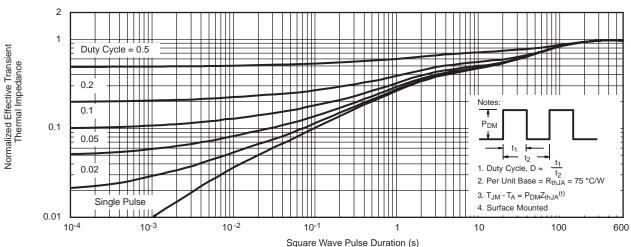


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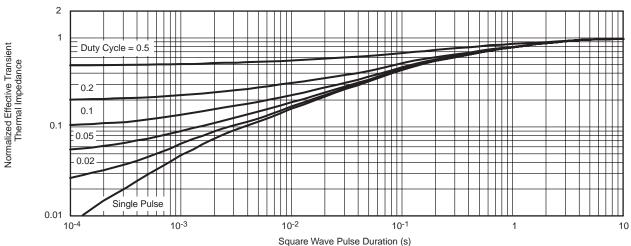
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Normalized Thermal Transient Impedance, Junction-to-Foot





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